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Typical Applications

The HMC214MS8 / HMC214MS8E is ideal for:

- WiMAX, 802.16
- Fixed Wireless Access
- Wireless Local Loop

Functional Diagram



HMC214MS8 / 214MS8E

HIGH IP3 GaAs MMIC MIXER, 2.4 - 4.0 GHz

Features

Input IP3: +34 dBm LO to RF Isolation: 28 dB +22 dBm Input P1dB No External Components Ultra Small MSOP Package: 14.8mm² Included in the HMC-DK003 Designer's Kit

General Description

The HMC214MS8(E) is a general purpose high dynamic range passive MMIC mixer in plastic surface mount 8 lead Mini Small Outline Package (MSOP) covering 2.4 to 4 GHz. Excellent input IP3 performance of +34 dBm for downcon-version and +31 dBm for upconversion is provided for WiMax and other 3.5 GHz applications at an LO drive of +17 dBm. With a 1dB compression of +22 dBm, the RF port will accept a wide range of input signal levels. Conversion loss is 10 dB typical and LO isolations are maintained at 25 to 30 dB. This miniature single-ended monolithic GaAs FET mixer does not require any external components or bias. The DC to 1 GHz IF frequency response will satisfy many transmit and receive frequency plans configured for low side LO. The HMC214MS8 & HMC214MS8E input IP3 performance coupled with its high P1dB rivals traditional active FET mixers while offering a much smaller 14.8mm² standard IC footprint and no DC bias.

Electrical Specifications, $T_A = +25^{\circ}C$, LO = +17dBm, $IF = 200 MHz^*$

Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range, RF		2.4 - 4.0		3.4 - 3.8			GHz
Frequency Range, LO		2.4 - 4.0			3.4 - 3.8		GHz
Frequency Range, IF		DC - 1 DC - 1		DC - 1		GHz	
Conversion Loss		10	12		10	11.5	dB
Noise Figure (SSB)		10	12		10	11.5	dB
LO to RF Isolation	18	30		20	28		dB
LO to IF Isolation	12	25		22	30		dB
IP3 (Input)	26	30		31	34		dBm
1 dB Gain Compression (Input)	18	21		20	22		dBm
LO Input Drive Level (Typical)	+15 to +19 +15 to +19		dBm				

*Unless otherwise noted, all measurements performed as a downconverter, with low side LO & IF = 200 MHz.

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Conversion Gain vs. Temperature @ LO = +17 dBm



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Conversion Gain vs. LO Drive



Upconverter Performance Conversion Gain @ LO = +17 dBm



Isolation @ LO = +17 dBm



Return Loss @ LO = +17 dBm



IF Bandwidth @ LO = +17 dBm



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EARTH FRIENDLY Input IP3 vs.

RoHS

Temperature, LO = +17 dBm



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Upconverter IP3 vs. LO Drive, IF = 200 MHz



Harmonics of LO

		nLO Spur	@ RF Port	
LO Freq (GHz)	1	2	3	4
2.6	35	26	42	39
2.8	30	26	47	40
3.0	29	26	46	42
3.2	28	29	42	хх
3.4 25 28 40 xx				хх
3.6	24	31	39	хх
LO = +17 dBm All values are in dBc below input LO level @ RF port.				





Input P1dB vs. Temperature @ LO = +17 dBm



MxN Spurious Outputs

	nLO				
mRF	0	1	2	3	4
0	xx	-4	-2	9	xx
1	9 0 37 39 35				35
2	73	66	49	65	77
3	97	98	104	85	91
4 xx 100 99 104 106					
RF Freq = 3.5 GHz @ -10 dBm LO Freq = 3.3 GHz @ +17 dBm All values in dBc relative to the IF output power.					

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Absolute Maximum Ratings

RF/IF Input	+27 dBm
LO Drive	+27 dBm
IF DC Current	±40 mA
Channel Temperature	150 °C
Continuous Pdiss (T=85 °C) (derate 3.69 mW/°C above 85 °C)	240 mW
Thermal Resistance (R _{TH}) (junction to lead)	270 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

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Package Information

0.38

TYP

.015

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC214MS8	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H214 XXXX
HMC214MS8E RoHS-compliant Low Stress Injection Molded Plastic 100% matte Sn MSL1 [2]		MSL1 ^[2]	<u>H214</u> XXXX	

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

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HMC214MS8 / 214MS8E

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ROHS V EARTH FRIENDLY

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	LO	This pin is DC coupled & matched to 50 Ohms. Blocking capacitors are required if line potential is not equal to 0V.	
2, 4	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
3, 6, 7	GND	This pin must be connected to RF ground.	
5	IF	This pin is DC coupled. For applications not requiring operation to DC this port should be DC blocked externally using a series capacitor. Choose value of capacitor to pass IF frequency desired. For operation to DC, this pin must not sink/source more than 40 mA of current or failure may result.	
8	RF	This pin is DC coupled and matched to 50 Ohms.	RF O

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Evaluation PCB



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List of Materials for Evaluation PCB 101830^[1]

Item	Description
J1 - J3	PCB Mount SMA RF Connector
U1	HMC214MS8 / HMC214MS8E Mixer
PCB ^[2]	101828 Eval Board

Reference this number when ordering complete evaluation PCB
Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

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